

3.0 A Positive Voltage Regulators

The LM323,A are monolithic integrated circuits which supply a fixed positive 5.0 V output with a load driving capability in excess of 3.0 A. These three-terminal regulators employ internal current limiting, thermal shutdown, and safe-area compensation. The A-suffix is an improved device with superior electrical characteristics and a 2% output voltage tolerance. These regulators are offered with a 0° to +125°C temperature range in a low cost plastic power package.

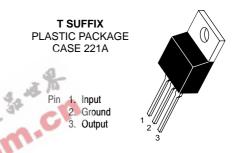
Although designed primarily as a fixed voltage regulator, these devices can be used with external components to obtain adjustable voltages and currents. These devices can be used with a series pass transistor to supply up to 15 A at 5.0 V.

- Output Current in Excess of 3.0 A
- Available with 2% Output Voltage Tolerance
- No External Components Required
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Thermal Regulation and Ripple Rejection Have Specified Limits

LM323, LM323A

3-AMPERE, 5 VOLT POSITIVE VOLTAGE REGULATORS

SEMICONDUCTOR TECHNICAL DATA

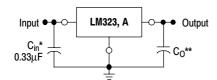


Heatsink surface is connected to Pin 2.

ORDERING INFORMATION

Device	Output Voltage Tolerance	Operating Temperature Range	Package	
LM323T	4%	$T_{.1} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	Plastic	
LM323AT	2%	1j=0 t0+125 C	Power	

Simplified Application



A common ground is required between the input and the output voltages. The input voltage must remain typically 2.5 V above the output voltage even during the low point on the input ripple voltage.

^{*}C_{in} is required if regulator is located an appreciable distance from power supply filter. (See Applications Information for details.)

^{**}C_O is not needed for stability; however, it does improve transient response.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V _{in}	20	Vdc
Power Dissipation	P _D	Internally Limited	W
Operating Junction Temperature Range	TJ	0 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Lead Temperature (Soldering, 10 s)	T _{solder}	300	°C

ELECTRICAL CHARACTERISTICS ($T_J = T_{low}$ to T_{high} [Note 1], unless otherwise noted.)

		LM323A		LM323				
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Output Voltage $(V_{in}=7.5 \text{ V}, \ 0 \leq I_{out} \leq 3.0 \text{ A}, \ T_J=25^{\circ}\text{C})$	Vo	4.9	5.0	5.1	4.8	5.0	5.2	V
Output Voltage $ (7.5 \text{ V} \leq \text{V}_{in} \leq 15 \text{ V}, \ 0 \leq \text{I}_{out} \leq 3.0 \text{ A}, \\ P \leq P_{max}) \ (\text{Note 2}) $	Vo	4.8	5.0	5.2	4.75	5.0	5.25	V
Line Regulation (7.5 V \leq V _{in} \leq 15 V, T _J = 25°C) (Note 3)	Reg _{line}	_	1.0	15	_	1.0	25	mV
Load Regulation $(V_{in}=7.5 \text{ V}, \ 0 \leq I_{out} \leq 3.0 \text{ A}, \ T_J=25^{\circ}\text{C})$ (Note 3)	Reg _{load}	-	10	50	,IT	10	100	mV
Thermal Regulation (Pulse = 10 ms, P = 20 W, T _A = 25°C)	Reg _{therm}	130	0.001	0.01	_	0.002	0.03	%V _O /W
Quiescent Current (7.5 V \leq V _{in} \leq 15 V, 0 \leq I _{out} \leq 3.0 A)	IB	7	3.5	10	-	3.5	20	mA
Output Noise Voltage (10 Hz \leq f \leq 100 kHz, T _J = 25°C)	V _N	_	40	_	-	40	-	μV_{rms}
Ripple Rejection (8.0 V \leq V _{in} \leq 18 V, I _{out} = 2.0A, f = 120 Hz, T _J = 25°C)	RR	66	75	_	62	75	-	dB
Short Circuit Current Limit $(V_{in} = 15 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_{in} = 7.5 \text{ V}, T_J = 25^{\circ}\text{C})$	I _{SC}	_ _	4.5 5.5	_ _	_ _	4.5 5.5	_ _	A
Long Term Stability	S	-	-	35	_	-	35	mV
Thermal Resistance, Junction-to-Case (Note 4)	$R_{\Theta JC}$	_	2.0	_	_	2.0	-	°C/W

NOTES: 1. T_{low} to T_{high} = 0° to +125°C

2. Although power dissipation is internally limited, specifications apply only for P ≤ P_{max} = 25 W.

3. Load and line regulation are specified at constant junction temperature. Pulse testing is required with a pulse width ≤ 1.0 ms and a duty cycle ≤ 5%.

4. Without a heatsink, the thermal resistance (R_{θJA} is 65°C/W). With a heatsink, the effective thermal resistance can approach the specified values of 2.0°C/W, depending on the efficiency of the heatsink.

Representative Schematic Diagram 2 Input 1.0k 1.0k 210 Q2 Q21 Q1 Q22 Q20 6.7V 16k 100 Q25 Q8 200 Q24 1.0k 300 Q26 ≶ 3.0k 10pF ≥ 10k Q3 **~**Q19 Q4 300 5.6k Q23 **C**Q16 13 Q5 0.12 010 520 50 200 Q12 Output 840 40pF_ 7.2k 6.0k ≥ 3.9k Q17 Q18 2.0k **▲** Q7 Q6 1.7k Q1 Q11

VOLTAGE REGULATOR PERFORMANCE

2.8k

The performance of a voltage regulator is specified by its immunity to changes in load, input voltage, power dissipation, and temperature. Line and load regulation are tested with a pulse of short duration (< $100~\mu s$) and are strictly a function of electrical gain. However, pulse widths of longer duration (> 1.0~m s) are sufficient to affect temperature gradients across the die. These temperature gradients can cause a change in the output voltage, in addition to changes by line and load regulation. Longer pulse widths and thermal gradients make it desirable to specify thermal regulation.

Q.

6.0k ≥

Thermal regulation is defined as the change in output voltage caused by a change in dissipated power for a specified time, and is expressed as a percentage output voltage change per watt. The change in dissipated power can be caused by a change in either input voltage or the load current. Thermal regulation is a function of IC layout and die attach techniques, and usually occurs within 10 ms of a change in power dissipation. After 10 ms, additional changes in the output voltage are due to the temperature coefficient of the device.

→ Gnd

Figure 1 shows the line and thermal regulation response of a typical LM323A to a 20 W input pulse. The variation of the output voltage due to line regulation is labeled \grave{A} and the thermal regulation component is labeled \acute{A} . Figure 2 shows the load and thermal regulation response of a typical LM323A to a 20 W load pulse. The output voltage variation due to load regulation is labeled \acute{A} and the thermal regulation component is labeled \acute{A} .

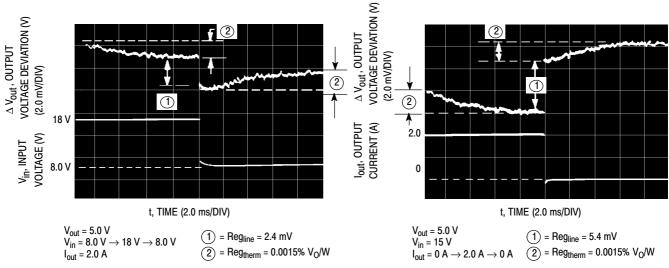
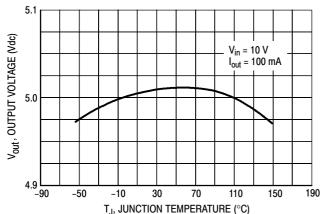


Figure 1. Line and Thermal Regulation

Figure 2. Load and Thermal Regulation



 $\label{eq:total_total_total} T_J, \mbox{ JUNCTION TEMPERATURE (°C)} \\ \mbox{ Figure 3. Temperature Stability}$

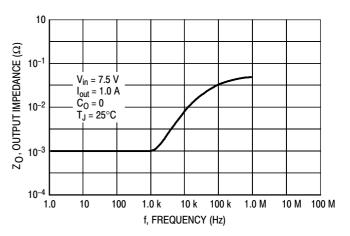


Figure 4. Output Impedance

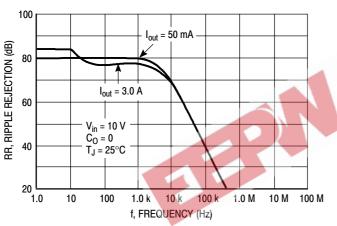


Figure 5. Ripple Rejection versus Frequency

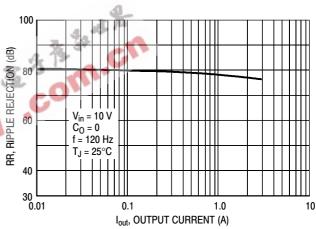


Figure 6. Ripple Rejection versus Output Current

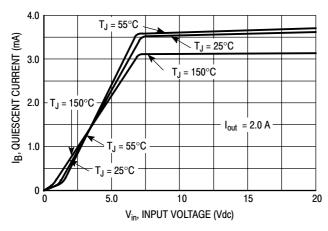


Figure 7. Quiescent Current versus Input Voltage

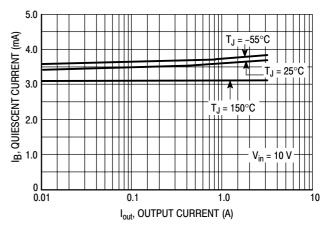


Figure 8. Quiescent Current versus
Output Current

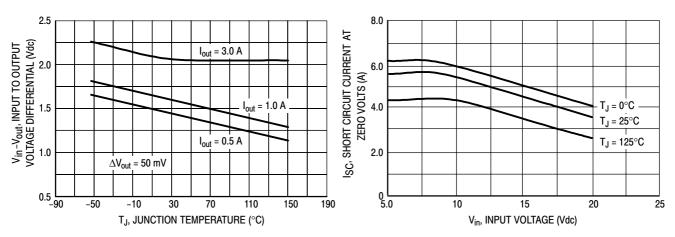


Figure 9. Dropout Voltage

Figure 10. Short Circuit Current

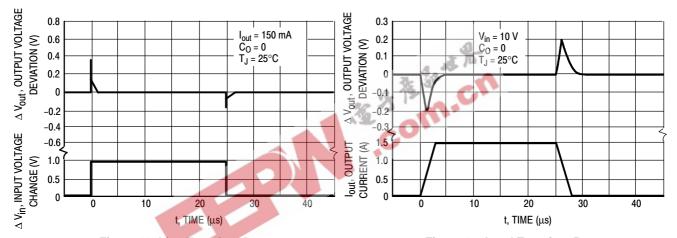


Figure 11. Line Transient Response

Figure 12. Load Transient Response

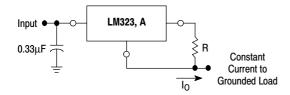
APPLICATIONS INFORMATION

Design Considerations

The LM323,A series of fixed voltage regulators are designed with Thermal Overload Protection that shuts down the circuit when subjected to an excessive power overload condition, Internal Short Circuit Protection that limits the maximum current the circuit will pass, and Output Transistor Safe–Area Compensation that reduces the output short circuit current as the voltage across the pass transistor is increased.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the

regulator is connected to the power supply filter with long wire lengths, or if the output load capacitance is large. An input bypass capacitor should be selected to provide good high–frequency characteristics to insure stable operation under all load conditions. A 0.33 μF or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with the shortest possible leads directly across the regulator's input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead.



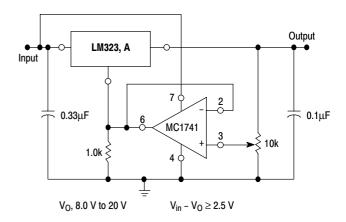
The LM323,A regulator can also be used as a current source when connected as above. Resistor R determines the current as follows:

$$I_0 = \frac{5.0 \text{ V}}{\text{R}} + I_{\text{B}}$$

 $\Delta I_{B}\,\cong\,0.7$ mA over line, load and temperature changes $I_B^- \cong 3.5 \text{ mA}$

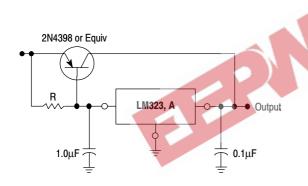
For example, a 2.0 A current source would require R to be a 2.5 Ω , 15 W resistor and the output voltage compliance would be the input voltage less 7.5 V.

Figure 13. Current Regulator



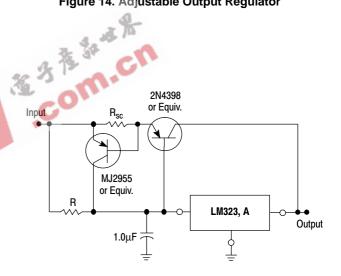
The addition of an operational amplifier allows adjustment to higher or intermediate values while retaining regulation characteristics. The minimum voltage obtainable with this arrangement is 3.0 V greater than the regulator voltage.

Figure 14. Adjustable Output Regulator



The LM323, A series can be current boosted with a PNP transistor. The 2N4398 provides current to 15 A. Resistor R in conjunction with the V_{BE} of the PNP determines when the pass transistor begins conducting; this circuit is not short circuit proof. Input-output differential voltage minimum is increased by the V_{BE} of the pass transistor.

Figure 15. Current Boost Regulator



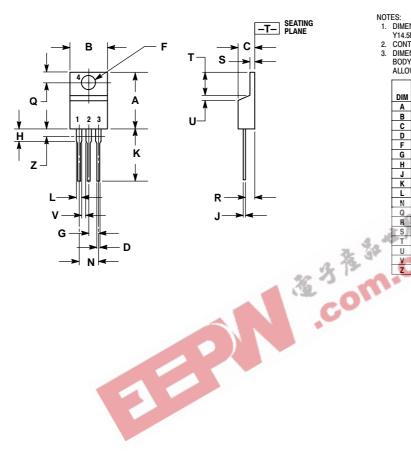
The circuit of Figure 16 can be modified to provide supply protection against short circuits by adding a short circuit sense resistor, RSC, and an additional PNP transistor. The current sensing PNP must be able to handle the short circuit current of the three-terminal regulator. Therefore, an 8.0 A power transistor is specified.

Figure 16. Current Boost with **Short Circuit Protection**

PACKAGE DIMENSIONS

T SUFFIX

PLASTIC PACKAGE CASE 221A-09 ISSUE AA



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T"	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
V	0.045		1.15		
Z	# Y	0.080		2.04	



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